

Notice of References Cited	Application/Control No. 10/753,103	Applicant(s)/Patent Under Reexamination CHEN ET AL.	
	Examiner Johannes P. Mondt	Art Unit 3663	Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
	B	US-			
	C	US-			
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FOREIGN PATENT DOCUMENTS

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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Matas et al, "Memory 1997", Section 10: "Flash Memory Technology", pages 10-1 - 10-15, ISBN: 1-877750-59-X (1997 Integrated Circuit Engineering Corporation); especially the discussion of the array based on the NAND cell, Figure 10-8 and page 10-5.
	V	D. Bohm, "Quantum Theory", 1951 (reprinted 1989, ISBN: 0-486-65969-0, Dover Publications), pages 438-440..
	W	Duffy et al, "Advanced process development using numerical simulation", in "Advanced MOS and Bi-Polar Devices" (IEE Colloquium on-), 14 February 1995, London (UK).
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.